NSN 5961-01-101-0291

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-101-0291 **Inclosure Material:** Metal **Overall Length:** 0.185 inches **Terminal Length:** 0.562 inches **Overall Diameter:** 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.230 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 20.0 collector to base voltage/static/emitter open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 0.45 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Precious Material And Location:** Terminals gold **Precious Material: Terminal Type And Quantity:** 12 pin Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: